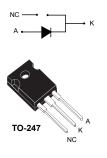


# STPSC16H065A

Datasheet

## 650 V power Schottky silicon carbide rectifier



### Features

- No or negligible reverse recovery
- Temperature independent switching behavior
- High forward surge capability
- Operating T<sub>i</sub> from -40 °C to 175 °C
- Power efficient product
- ECOPACK<sup>®</sup>2 compliant

### **Applications**

- DC/DC converter
- High frequency inverter
- Boost PFC function

## Description

The STPSC16H065A SiC diode is an ultrahigh performance power Schottky diode. It is manufactured using a silicon carbide substrate. The wide band gap material allows the design of a Schottky diode structure with a 650 V rating. Due to the Schottky construction, no recovery is shown at turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature.

Especially suited for use in PFC applications, this ST SiC diode, packaged in TO-247, will boost the performance in hard switching conditions. Its high forward surge capability ensures a good robustness during transient phases.

Product status link	
STPSC16H065A	

Product summary				
I <sub>F(AV)</sub>	16 A			
V <sub>RRM</sub>	650 V			
T <sub>j</sub> (max.)	175 °C			
V <sub>F</sub> (typ.)	1.56 V			

Product label

## 1 Characteristics

### Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Pa	Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage $T_j = -40 \text{ °C to } +175 \text{ °C}$		650	V
I <sub>F(RMS)</sub>	Forward rms current	22	А	
I <sub>F(AV)</sub>	Average forward current $T_c = 115 \circ C^{(1)}$ , DC current		16	А
I <sub>FSM</sub> Su	Surge non repetitive forward current	$t_p$ = 10 ms sinusoidal, $T_c$ = 25 °C	120	
		$t_p$ = 10 ms sinusoidal, $T_c$ = 125 °C	105	Α
		$t_p$ = 10 µs square, $T_c$ = 25 °C	800	
I <sub>FRM</sub>	Repetitive peak forward current $T_c = 115 \ ^{\circ}C^{(1)}$ $T_j = 175 \ ^{\circ}C$ $\delta = 0.1$		66	Α
T <sub>stg</sub>	Storage temperature range	-55 to +175	°C	
Тj	Operating junction temperature	-40 to +175	°C	

1. Value based on  $R_{th(j-c)}$  max.

#### Table 2. Thermal resistance parameters

Symbol	Parameter	Va	lue	Unit
Symbol	F al allielei	Тур.	Max.	Onit
R <sub>th(j-c)</sub>	Junction to case	0.95	1.5	°C/W

For more information, please refer to the following application note:

AN5088: Rectifiers thermal management, handling and mounting recommendations

#### Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Deverse leakage eurrent	T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>	-	12	140	μA
'R`	Reverse leakage current	T <sub>j</sub> = 150 °C		-	120	560	
V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	Ennuard voltage drep	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 16 A	-	1.56	1.75	V
	Forward voltage drop	T <sub>j</sub> = 150 °C		-	1.98	2.50	

1. Pulse test:  $t_p = 10 \text{ ms}, \delta < 2\%$ 

2. Pulse test:  $t_p = 500 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses, use the following equation:

 $P = 1.35 \text{ x } I_{F(AV)} + 0.07 \text{ x } I_{F}^{2}(RMS)$ 

For more information, please refer to the following application notes related to the power losses:

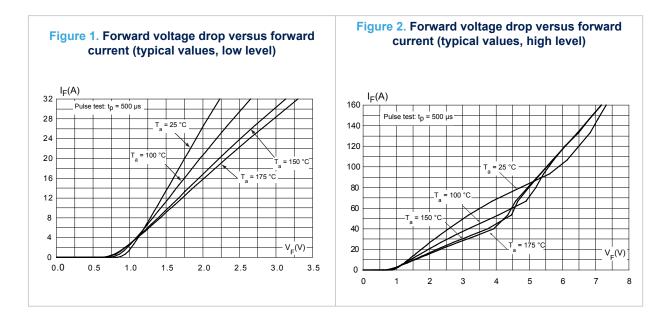
- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

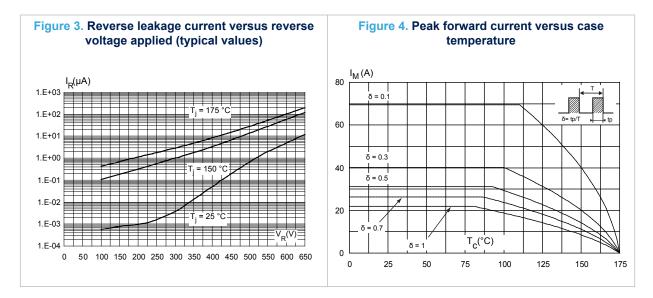
Symbol	Parameter	Test conditions	Тур.	Unit		
Q <sub>Cj</sub> <sup>(1)</sup>	Total capacitive charge	V <sub>R</sub> = 400 V	41	nC		
Ci	Total conceitance	$V_{R}$ = 0 V, T <sub>c</sub> = 25 °C, F = 1 MHz	750	<b>~</b> Г		
Uj	Total capacitance	$V_{R}$ = 300 V, T <sub>c</sub> = 25 °C, F = 1 MHz	76	pF		
1. Maat aaay	Must accurate value for the conscitive charge: $Q_{\mu}(V_{\mu}) = \int C_{\mu}(V) dV$					

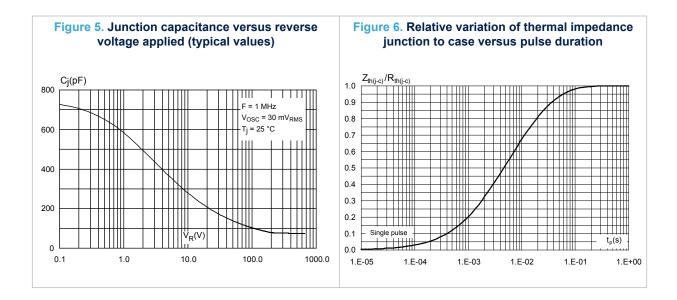
#### Table 4. Dynamic electrical characteristics

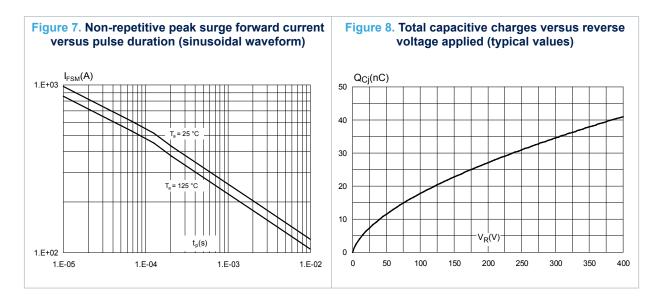
Most accurate value for the capacitive charge:  $Q_{Cj}(V_R) = \int_0^\infty C_j(V)dV$ 

### **1.1** Characteristics (curves)









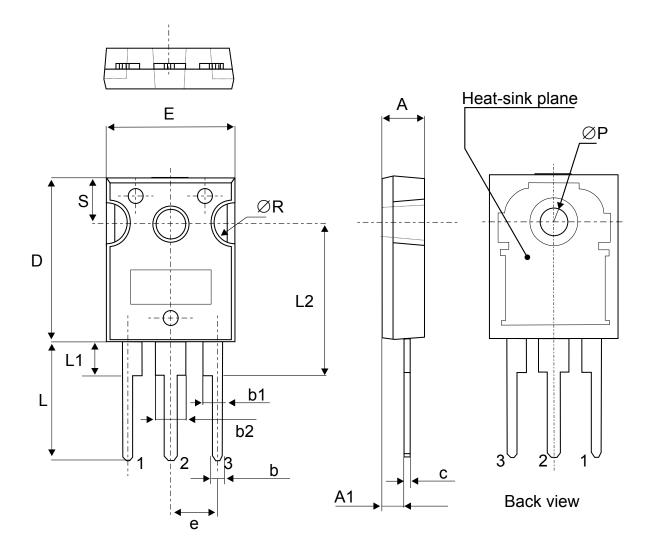
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.

## 2.1 TO-247 package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N·m
- Maximum torque value: 1.0 N·m





			Dimer	nsions		
Ref.		Millimeters		Incl	nes (for reference o	only)
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	4.85		5.15	0.191		0.203
A1	2.20		2.60	0.086		0.102
b	1.00		1.40	0.039		0.055
b1	2.00		2.40	0.078		0.094
b2	3.00		3.40	0.118		0.133
С	0.40		0.80	0.015		0.031
D	19.85		20.15	0.781		0.793
E	15.45		15.75	0.608		0.620
е	5.30	5.45	5.60	0.209	0.215	0.220
L	14.20		14.80	0.559		0.582
L1	3.70		4.30	0.145		0.169
L2		18.50			0.728	
ØP	3.55		3.65	0.139		0.143
ØR	4.50		5.50	0.177		0.217
S	5.30	5.50	5.70	0.209	0.216	0.224

#### Table 5. TO-247 package mechanical data



# **3** Ordering information

Table	6.	Ordering	information
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Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPSC16H065AW	STPSC16H065AW	TO-247	4.43 g	30	Tube

## **Revision history**

## Table 7. Document revision history

Date	Version	Changes
08-Oct-2018	1	Initial release.



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